



## OPA300, OPA2300 OPA301, OPA2301

SBOS271D - MAY 2003 - REVISED JUNE 2007

## Low-Noise, High-Speed, 16-Bit Accurate, CMOS OPERATIONAL AMPLIFIER

## **FEATURES**

- High Bandwidth: 150MHz
- 16-Bit Settling in 150ns
- Low Noise: 3nV/√Hz
- Low Distortion: 0.003%
- Low Power: 9.5mA (typ) on 5.5V
- Shutdown to 5μA
- Unity-Gain Stable
- Excellent Output Swing: (V+) – 100mV to (V–) + 100mV
- Single Supply: +2.7V to +5.5V
- Tiny Packages: MSOP and SOT23

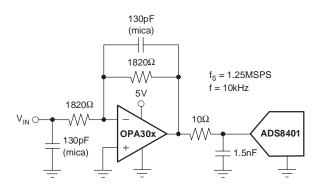
## **APPLICATIONS**

- 16-Bit ADC Input Drivers
- Low-Noise Preamplifiers
- IF/RF Amplifiers
- Active Filtering

## DESCRIPTION

The OPA300 and OPA301 series high-speed, voltage-feedback, CMOS operational amplifiers are designed for 16-bit resolution systems. The OPA300/OPA301 series are unity-gain stable and feature excellent settling and harmonic distortion specifications. Low power applications benefit from low quiescent current. The OPA300 and OPA2300 feature a digital shutdown (Enable) function to provide additional power savings during idle periods. Optimized for single-supply operation, the OPA300/OPA301 series offer superior output swing and excellent common-mode range.

The OPA300 and OPA301 series op amps have 150MHz of unity-gain bandwidth, low  $3nV/\sqrt{Hz}$  voltage noise, and 0.1% settling within 30ns. Single-supply operation from 2.7V (±1.35V) to 5.5V (±2.75V) and an available shutdown function that reduces supply current to 5µA are useful for portable low-power applications. The OPA300 and OPA301 are available in SO-8 and SOT-23 packages. The OPA2300 is available in MSOP-10, and the OPA2301 is available in SO-8 and SOT-23 packages are specified over the industrial temperature range of  $-40^{\circ}$ C to  $+125^{\circ}$ C.



#### Typical Application

**A** 

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#### PACKAGE/ORDERING INFORMATION(1)

PRODUCT	PACKAGE-LEAD	PACKAGE DESIGNATOR	PACKAGE MARKING
OPA300	SO-8	D	300A
OPA300	SOT23-6	DBV	A52
OPA301	SO-8	D	301A
OPA301	SOT23-5	DBV	AUP
OPA2300	MSOP-10	DGS	C01
OPA2301	SO-8	D	OPA2301A
OPA2301	MSOP-8	DGK	OAWM

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

#### **ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range unless otherwise noted<sup>(1)</sup>

Power Supply V+
Signal Input Terminals <sup>(2)</sup> , Voltage 0.5V to (V+) + 0.5V
Current ±10mA
Open Short-Circuit Current <sup>(3)</sup> Continuous
Operating Temperature Range55°C to +125°C
Storage Temperature Range60°C to +150°C
Junction Temperature
ESD Ratings
Human Body Model (HBM)
Charged-Device Model (CDM)

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

- (2) Input terminals are diode clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails should be current limited to 10mA or less.
- (3) Short-circuit to ground; one amplifier per package.

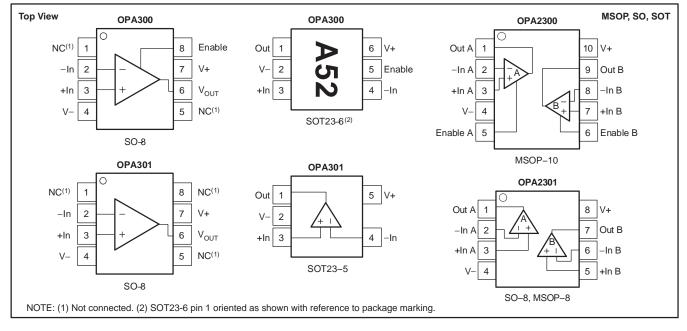
#### **PIN ASSIGNMENTS**

### **ELECTROSTATIC DISCHARGE SENSITIVITY**



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.



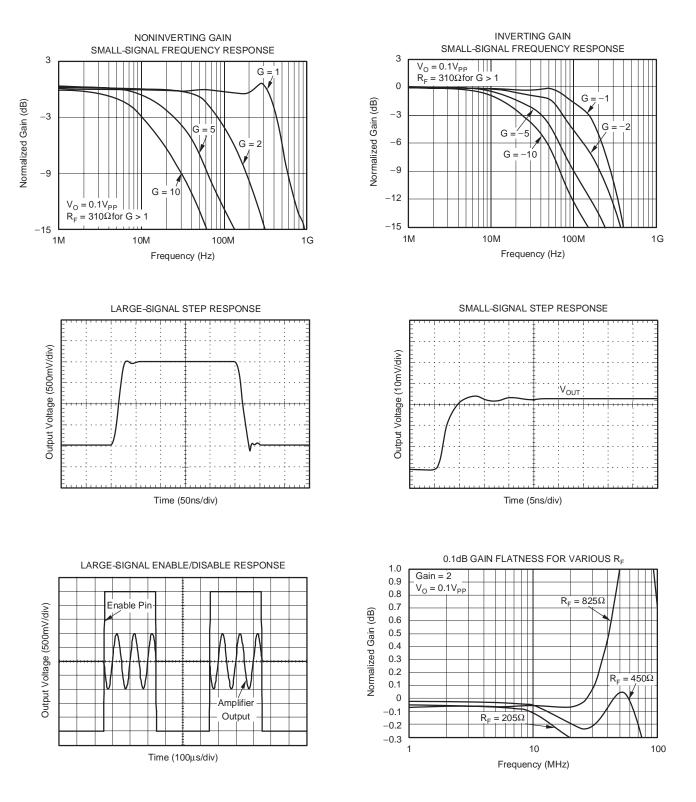
# **ELECTRICAL CHARACTERISTICS:** $V_S = 2.7V$ to 5.5V **Boldface** limits apply over the temperature range, $T_A = -40^{\circ}C$ to $+125^{\circ}C$ . All specifications at $T_A = +25^{\circ}C$ , $R_L = 2k\Omega$ connected to $V_S/2$ , $V_{OUT} = V_S/2$ , and $V_{CM} = V_S/2$ , unless otherwise noted.

		u to v9/2, v001 – v9/2, and v0M – v9	O OP			
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNITS
OFFSET VOLTAGE Input Offset Voltage Over Temperature	Vos	$V_{S} = 5V$		1	5 7	m∨ mV
Drift vs. Power Supply Channel Separation, dc f = 5MHz	dV <sub>OS</sub> /dT PSRR	V <sub>S</sub> = 2.7V to 5.5V, V <sub>CM</sub> < (V+) –0.9V		<b>2.5</b> <b>50</b> 140 100	200	μ <b>V/°C</b> μ <b>V/V</b> dB dB
INPUT VOLTAGE RANGE Common-Mode Voltage Range Common-Mode Rejection Ratio	V <sub>CM</sub> CMRR	(V−) − 0.2V < V <sub>CM</sub> < (V+) − 0.9V	(V–) – 0.2 66	80	(V+) – 0.9	∨ dB
INPUT BIAS CURRENT	I <sub>B</sub>			±0.1 ±0.5	±5 ±5	pA pA
Input Offset Current INPUT IMPEDANCE Differential	los			10 <sup>13</sup>    3	το	Ω    pF
Common-Mode NOISE				10 <sup>13</sup>    6		Ω    pF
Input Voltage Noise, f = 0.1Hz to 1MHz Input Voltage Noise Density, f > 1MHz Input Current Noise Density, f < 1kHz Differential Gain Error Differential Phase Error	e <sub>n</sub> i <sub>n</sub>	NTSC, R <sub>L</sub> = 150Ω NTSC, R <sub>L</sub> = 150Ω		40 3 1.5 0.01 0.1		µV <sub>PP</sub> nV/√Hz fA/√Hz % ∘
OPEN-LOOP GAIN Open-Loop Voltage Gain Over Temperature	AOL	$V_{S} = 5V, R_{L} = 2k\Omega, 0.1V < V_{O} < 4.9V$ $V_{S} = 5V, R_{L} = 2k\Omega, 0.1V < V_{O} < 4.9V$ $V_{S} = 5V, R_{L} = 100\Omega, 0.5V < V_{O} < 4.5V$	95 <b>90</b> 95	106 106		dB <b>dB</b> dB
Over Temperature		$V_{S} = 5V, R_{L} = 100\Omega, 0.5V < V_{O} < 4.5V$	90			dB
OUTPUT Voltage Output Swing from Rail Short-Circuit Current Open-Loop Output Impedance Capacitive Load Drive	I <sub>SC</sub> RO CLOAD	$\begin{aligned} R_L &= 2k\Omega, \ A_{OL} > 95dB \\ R_L &= 100\Omega, \ A_{OL} > 95dB \\ I_O &= 0, \ f = 1MHz \end{aligned}$	See Ti	75 300 70 20 ypical Charact	100 500	mV mV mA Ω
FREQUENCY RESPONSE Gain-Bandwidth Product Slew Rate Settling Time, 0.01% 0.1% Overload Recovery Time	GBW SR <sup>†</sup> S	G = +1 $V_S = 5V, 2V$ Step, $G = +1$ Gain = -1		150 80 90 30 30		MHz V/μs ns ns ns %
Total Harmonic Distortion + Noise <b>POWER SUPPLY</b> Specified Voltage Range Operating Voltage Range Quiescent Current (per amplifier) <b>Over Temperature</b>	THD+N VS IQ	$V_{S} = 5V, V_{O} = 3V_{PP}, G = +1, f = 1kHz$ $I_{O} = 0$	2.7	0.003 2.7 to 5.5 9.5	5.5 12 <b>13</b>	V V mA <b>mA</b>
SHUTDOWN <sup>t</sup> OFF <sup>t</sup> ON           VL (shutdown)           VH (amplifier is active)           IQSD (per amplifier)			(V–) – 0.2 (V–) + 2.5	40 5 3	(V-) + 0.8 (V+) + 0.2 10	ns μs V V μA
TEMPERATURE RANGE Specified Range Operating Range Storage Range Thermal Resistance SO-8, MSOP–8, MSOP-10 SOT23-5, SOT23-6	θ <sub>JA</sub>		-40 -55 -60	150 200	+125 +125 +150	လိုသို လိုသို လိုသိုသို လို



## **TYPICAL CHARACTERISTICS**

All specifications at T<sub>A</sub> = 25°C, V<sub>S</sub> = 5V, and R<sub>L</sub> = 150 $\Omega$  connected to V<sub>S</sub>/2 unless otherwise noted.



2nd-Harmonic

2nd-Harmonic

Current Noise

100k

1M

1M

10k

10

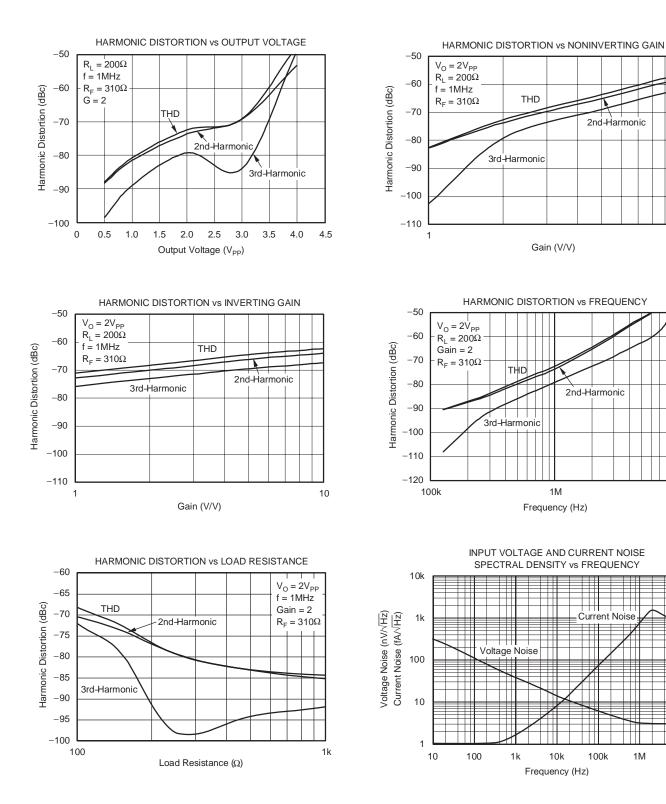
10M

SBOS271D - MAY 2003 - REVISED JUNE 2007

## **TYPICAL CHARACTERISTICS (continued)**

**FRUMENTS** www.ti.com

All specifications at  $T_A = 25^{\circ}C$ ,  $V_S = 5V$ , and  $R_L = 150\Omega$  connected to  $V_S/2$  unless otherwise noted.



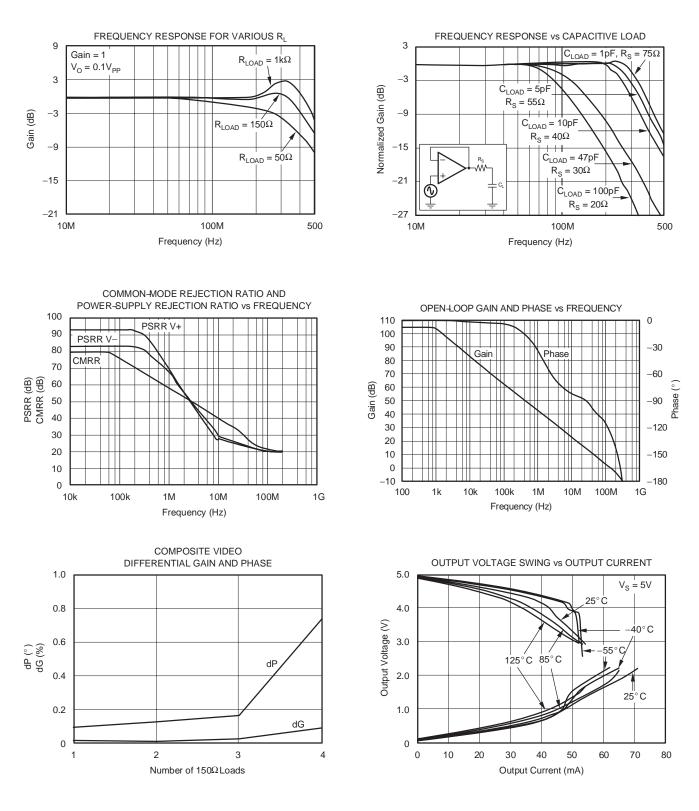
5

10M



## **TYPICAL CHARACTERISTICS (continued)**

All specifications at T<sub>A</sub> = 25°C, V<sub>S</sub> = 5V, and R<sub>L</sub> = 150 $\Omega$  connected to V<sub>S</sub>/2 unless otherwise noted.



## OPA300, OPA2300 OPA301, OPA2301

100 120 140

1

V<sub>S</sub> = 5.5V

 $V_{S} = 5V$ 

 $V_{S} = 5.5V$ 

120 140

100

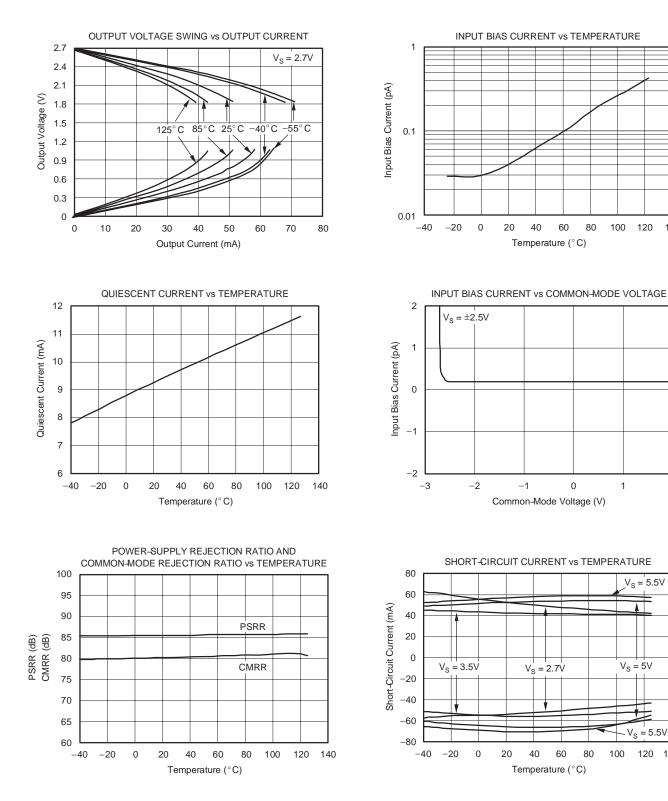
2

SBOS271D - MAY 2003 - REVISED JUNE 2007

## **TYPICAL CHARACTERISTICS (continued)**

45 RUMENTS www.ti.com

All specifications at  $T_A = 25^{\circ}$ C,  $V_S = 5$ V, and  $R_L = 150\Omega$  connected to  $V_S/2$  unless otherwise noted.



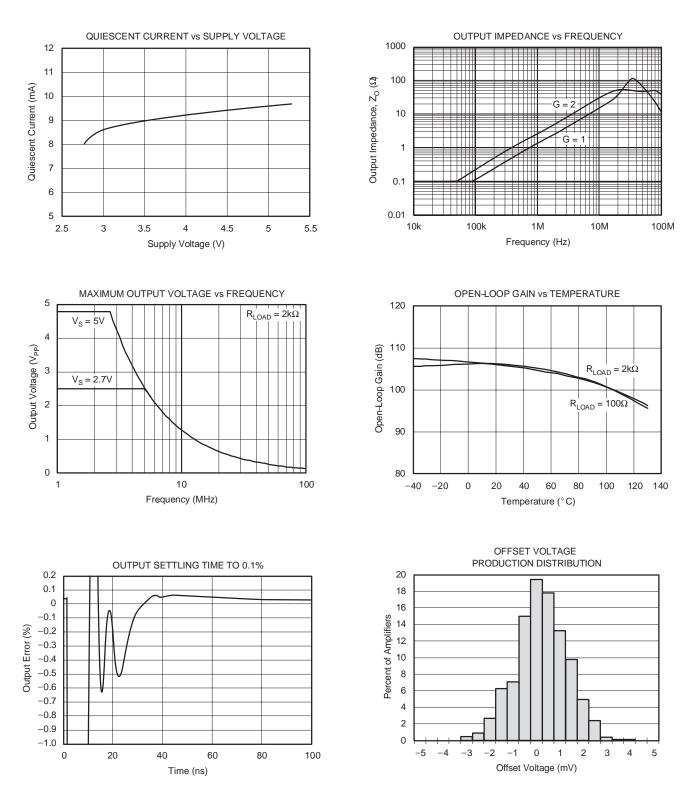
#### OPA300, OPA2300 OPA301, OPA2301



SBOS271D - MAY 2003 - REVISED JUNE 2007

## **TYPICAL CHARACTERISTICS (continued)**

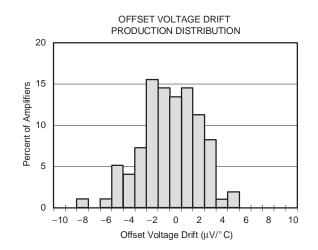
All specifications at T<sub>A</sub> = 25°C, V<sub>S</sub> = 5V, and R<sub>L</sub> = 150 $\Omega$  connected to V<sub>S</sub>/2 unless otherwise noted.





## **TYPICAL CHARACTERISTICS (continued)**

All specifications at T<sub>A</sub> = 25°C, V<sub>S</sub> = 5V, and R<sub>L</sub> = 150 $\Omega$  connected to V<sub>S</sub>/2 unless otherwise noted.





## **APPLICATIONS INFORMATION**

The OPA300 and OPA301 series of single-supply CMOS op amps are designed to interface with high-speed 16-bit analog-to-digital converters (ADCs). Featuring wide 150MHz bandwidth, fast 150ns settling time to 16 bits, and high open loop gain, this series offers excellent performance in a small SO-8 and tiny SOT23 packages.

## THEORY OF OPERATION

The OPA300 and OPA301 series op amps use a classic two-stage topology, shown in Figure 1. The differential input pair is biased to maximize slew rate without compromising stability or bandwidth. The folded cascode adds the signal from the input pair and presents a differential signal to the class AB output stage. The class AB output stage allows rail- to-rail output swing, with high-impedance loads  $(> 2k\Omega)$ , typically 100mV from the supply rails. With  $10\Omega$ loads, a useful output swing can be achieved and still maintain high open-loop gain. See the typical characteristic Output Voltage Swing vs Output Current.

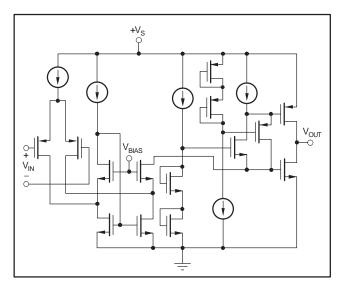


Figure 1. OPA30x Classic Two-Stage Topology

#### **OPERATING VOLTAGE**

OPA300/OPA301 series op amp parameters are fully specified from +2.7V to +5.5V. Supply voltages higher than 5.5V (absolute maximum) can cause permanent damage to the amplifier. Many specifications apply from -40°C to +125°C. Parameters that vary significantly with operating voltages or temperature are shown in the Typical Characteristics.

#### PCB LAYOUT

As with most high-speed operational amplifiers, board layout requires special attention to maximize AC and DC performance. Extensive use of ground planes, short lead lengths, and high-quality bypass capacitors will minimize leakage that can compromise signal quality. Guard rings applied with potential as near to the input pins as possible help minimize board leakage.

#### INPUT AND ESD PROTECTION

All OPA300/OPA301 series op amps' pins are staticprotected with internal ESD protection diodes tied to the supplies, as shown in Figure 2. These diodes will provide overdrive protection if the current is externally limited to 10mA, as stated in the Absolute Maximum Ratings. Any input current beyond the Absolute Maximum Ratings, or long-term operation at maximum ratings, will shorten the lifespan of the amplifier.

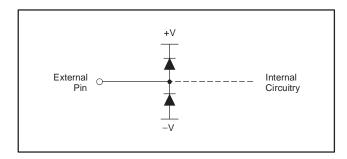


Figure 2. ESD Protection Diodes

#### ENABLE FUNCTION

The shutdown function of the OPA300 and OPA2300 is referenced to the negative supply voltage of the operational amplifier. A logic level HIGH enables the op amp. A valid logic HIGH is defined as 2.5V above the negative supply applied to the enable pin. A valid logic LOW is defined as < 0.8V above the negative supply pin. If dual or split power supplies are used, care should be taken to ensure logic input signals are properly referred to the negative supply voltage. If this pin is not connected to a valid high or low voltage, the internal circuitry will pull the node high and enable the part to function.

The logic input is a high-impedance CMOS input. For battery-operated applications, this feature may be used to greatly reduce the average current and extend battery life. The enable time is  $10\mu$ s; disable time is  $1\mu$ s. When disabled, the output assumes a high-impedance state. This allows the OPA300 to be operated as a gated amplifier, or to have its output multiplexed onto a common analog output bus.



#### DRIVING CAPACITIVE LOADS

When using high-speed operational amplifiers, it is extremely important to consider the effects of capacitive loading on amplifier stability. Capacitive loading will interact with the output impedance of the operational amplifier, and depending on the capacitor value, may significantly decrease the gain bandwidth, as well as introduce peaking. To reduce the effects of capacitive loading and allow for additional capacitive load drive, place a series resistor between the output and the load. This will reduce available bandwidth, but permit stable operation with capacitive loading. Figure 3 illustrates the recommended relationship between the resistor and capacitor values.

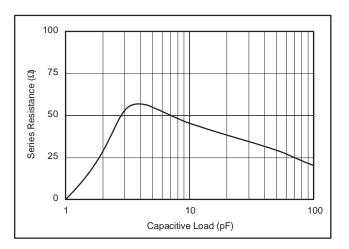


Figure 3. Recommended R<sub>S</sub> and C<sub>L</sub> Combinations

Amplifiers configured in unity gain are most susceptible to stability issues. The typical characteristic, Frequency Response vs Capacitive Load, describes the relationship between capacitive load and stability for the OPA300/OPA301 In unity series. gain. the OPA300/OPA301 series is capable of driving a few picofarads of capacitive load without compromising stability. Board level parasitic capacitance can often fall into the range of a picofarad or more, and should be minimized through good circuit-board layout practices avoid compromising the stability of to the OPA300/OPA301. For more information on detecting parasitics during testing, see the Application Note Measuring Board Parasitics in High-Speed Analog Design (SBOA094), available at the TI web site www.ti.com.

SBOS271D - MAY 2003 - REVISED JUNE 2007

#### DRIVING A 16-BIT ADC

The OPA300/OPA301 series feature excellent THD+noise, even at frequencies greater than 1MHz, with a 16-bit settling time of 150ns. Figure 4 shows a total single supply solution for high-speed data acquisition. The OPA300/OPA301 directly drives the ADS8401, a 1.25 mega sample per second (MSPS) 16-bit data converter. The OPA300/OPA301 is configured in an inverting gain of 1, with a 5V single supply. Results of the OPA300/OPA301 performance are summarized in Table 1.

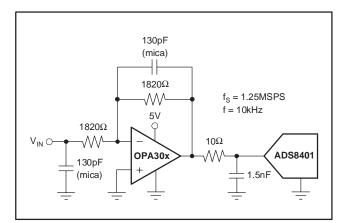


Figure 4. The OPA30x Drives the 16-Bit ADS8401

PARAMETER	RESULTS (f = 10kHz)
THD	-99.3dB
SFDR	101.2dB
THD+N	84.2dB
SNR	84.3dB

Table 1. OPA30x Performance Results Driving a 1.25MSPS ADS8401



11-Apr-2013

#### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
OPA2300AIDGSR	ACTIVE	VSSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	C01	Samples
OPA2300AIDGSRG4	ACTIVE	VSSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	C01	Samples
OPA2300AIDGST	ACTIVE	VSSOP	DGS	10	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	C01	Samples
OPA2300AIDGSTG4	ACTIVE	VSSOP	DGS	10	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	C01	Samples
OPA2301AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 2301A	Samples
OPA2301AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 2301A	Samples
OPA2301AIDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OAWM	Samples
OPA2301AIDGKRG4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OAWM	Samples
OPA2301AIDGKT	ACTIVE	VSSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OAWM	Samples
OPA2301AIDGKTG4	ACTIVE	VSSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OAWM	Samples
OPA2301AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 2301A	Samples
OPA2301AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 2301A	Samples
OPA300AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 300A	Samples
OPA300AIDBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	A52	Samples
OPA300AIDBVRG4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	A52	Samples
OPA300AIDBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	A52	Samples
OPA300AIDBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	A52	Samples



11-Apr-2013

Orderable Device	Status	Package Type	Package Drawing		Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
OPA300AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 300A	Samples
OPA301AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 301A	Samples
OPA301AIDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	AUP	Samples
OPA301AIDBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	AUP	Samples
OPA301AIDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	AUP	Samples
OPA301AIDBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	AUP	Samples
OPA301AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 301A	Samples
OPA301AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 301A	Samples
OPA301AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 301A	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



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### PACKAGE OPTION ADDENDUM

11-Apr-2013

<sup>(4)</sup> Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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## PACKAGE MATERIALS INFORMATION

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#### TAPE AND REEL INFORMATION



\*All dimensions are nominal



#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



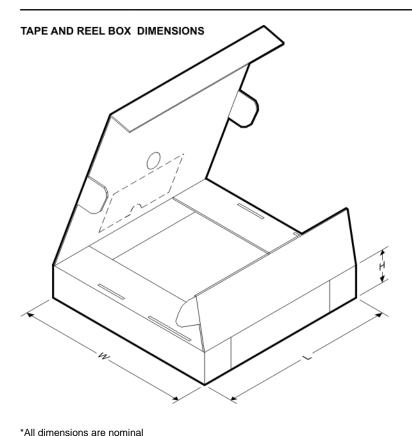
Device	Package	Package	Pins	SPQ	Reel	Reel	A0	B0	K0	P1	w	Pin1
Devide	Туре	Drawing		5	Diameter		(mm)	(mm)	(mm)	(mm)	(mm)	Quadrant
OPA2300AIDGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2300AIDGST	VSSOP	DGS	10	250	180.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2301AIDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2301AIDGKT	VSSOP	DGK	8	250	180.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2301AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA301AIDBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
OPA301AIDBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
OPA301AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TEXAS INSTRUMENTS

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## PACKAGE MATERIALS INFORMATION

19-Nov-2012



All ulmensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA2300AIDGSR	VSSOP	DGS	10	2500	367.0	367.0	35.0
OPA2300AIDGST	VSSOP	DGS	10	250	210.0	185.0	35.0
OPA2301AIDGKR	VSSOP	DGK	8	2500	367.0	367.0	35.0
OPA2301AIDGKT	VSSOP	DGK	8	250	210.0	185.0	35.0
OPA2301AIDR	SOIC	D	8	2500	367.0	367.0	35.0
OPA301AIDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
OPA301AIDBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
OPA301AIDR	SOIC	D	8	2500	367.0	367.0	35.0

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
  - This drawing is subject to change without notice. Β.
  - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side. C.
  - D. Falls within JEDEC MO-178 Variation AA.



DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.

- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
  - A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
  - E Falls within JEDEC MO-178 Variation AB, except minimum lead width.



#### LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.

- D Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



DGS (S-PDSO-G10)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-187 variation BA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
   E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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